

CSD2040CT/CSD2045CT

20A Surface Mount Low Barrier Diode

■ Features

- · Low forward voltage drop.
- Excellent high temperature stability.
- Fast switching capability.
- Suffix "G" indicates Halogen-free part, ex.CSD2040CTG.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

■ Mechanical data

 $\bullet \ \mathsf{Epoxy} : \mathsf{UL94}\text{-}\mathsf{V0} \ \mathsf{rated} \ \mathsf{flame} \ \mathsf{retardant}.$

• Case: Molded plastic, DPAK / TO-252.

 Lead: Solder plated, solderable per MIL-STD-750, Method 2026.

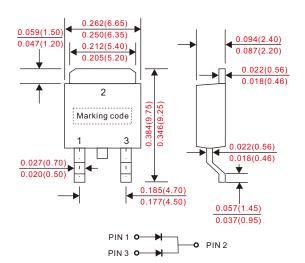
• Polarity: Indicated by cathode band.

• Mounting Position : Any.

• Weight: Approximated 0.34 gram.

Outline

DPAK(TO-252)



Dimensions in inches and (millimeters)

■ Maximum ratings and electrical characteristics

Rating at 25° C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

<u> </u>					
Parameter	Conditions	Symbol	CSD2040CT	CSD2045CT	
Marking code			CSD2040CT	CSD2045CT	UNIT
Peak repetitive reverse voltage		V _{RRM}			
Working peak reverse voltage		V_{RWM}	40	45	V
DC blocking voltage		V_{RM}			
Forward rectified current	T _c = 110°C	Io	20		Α
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I _{FSM}	120		А
Peak repetitive reverse surge current	2us - 1kHz	I _{RRM}	2		Α
Thermal resistance(1)	Junction to case	R _{eJC}	2		°C/W
Operating and Storage temperature		T _J , T _{STG}	-65 ~ +150		°C

Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
Farmenday No. 10 and 10 and	$I_F = 10A, T_J = 25^{\circ}C$				540	mV
Forward voltage drop	I _F = 10A, T _J = 125°C	0A, T _J = 125°C		430	490	
Davage augment	$V_R = V_{RRM} T_J = 25^{\circ}C$				0.5	mA
Reverse current	$V_R = V_{RRM} T_J = 125^{\circ}C$	I _R			100	

Note: 1.Thermal resistance from junction to case per leg, with heatsink size(1.35" x 0.95" x 0.18") Al-plate.

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■ Rating and characteristic curves

Fig. 1 - Forward Current Derating Curve

Fig. 2 - Instantaneous Forward Characteristics (per diode)

100

T_A=150°C

T_A=150°C

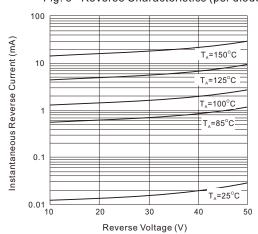
T_A=150°C

T_A=25°C

T_A=25°C

Instantaneous Forward Voltage (Volts)

Fig. 3 - Reverse Characteristics (per diode)



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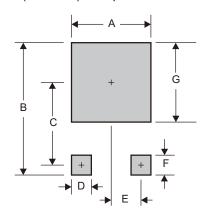
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■ DPAK(TO-252) foot print



Α	В	С	D	E	F	G
0.276 (7.00)	0.457 (11.60)	0.272 (6.90)	0.059 (1.50)	0.091 (2.30)	0.098 (2.50)	0.276 (7.00)

Dimensions in inches and (millimeters)

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